

SURFACE MOUNT SILICON RECTIFIER DIODES

VOLTAGE RANGE: 50 - 1000V CURRENT: 2.0 A

Features

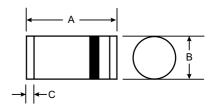
- Diffused Junction
- Low Forward Voltage Drop
- High Current Capability
- High Reliability
- High Surge Current Capability

Mechanical Data

- Case:LL41(DO-213AB)
- Terminals:Plated terminals, solderable per
- MIL-STD-202, Method 208
- Polarity:Red Color band on body denotes cathode
- Mounting position :Any
- Weight:0.12grams







LL41/ DO-213AB						
Dim	Min	Max				
Α	4.80	5.20				
В	2.40	2.60				
С	0.55 Nominal					
All Dimensions in mm						

Maximum Ratings and Electrical Characteristics T_A = 25°C unless otherwise specified

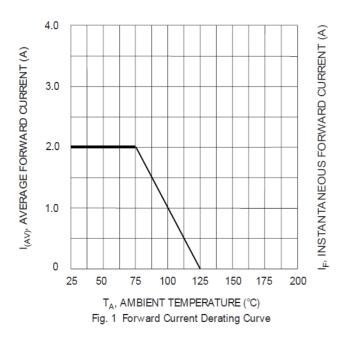
Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

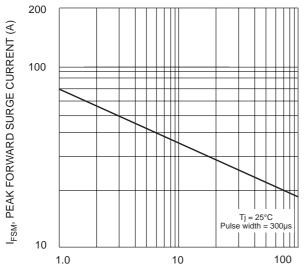
Characteristic	Symbol	SM201	SM202	SM203	SM204	SM205	SM206	SM207	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	Vrrm Vrwm Vr	50	100	200	400	600	800	1000	V
RMS Reverse Voltage	VR(RMS)	35	70	140	280	420	560	700	V
Average Rectified Output Current (Note 1) @T _A = 75°C	lo	2.0						Α	
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	IFSM	70						Α	
Forward Voltage @I _F = 2.0A	VFM	1.0							V
	IRM	5.0 50						μΑ	
Typical Junction Capacitance (Note 2)	Cj				20				pF
Typical Thermal Resistance Junction to Ambient (Note 1)	R heta JA				40				K/W
Operating Temperature Range	Tj			-(65 to +12	5			°C
Storage Temperature Range	Тѕтс	-65 to +150					°C		

Note: 1. Leads maintained at ambient temperature at a distance of 9.5mm from the case

2. Measured at 1.0 MHz and Applied Reverse Voltage of 4.0V D.C.







NUMBER OF CYCLES AT 60Hz Fig. 3 Maximum Non-Repetitive Surge Current

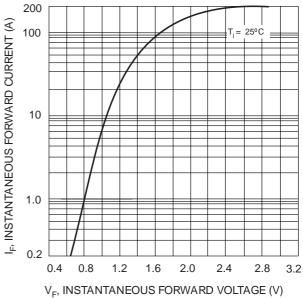
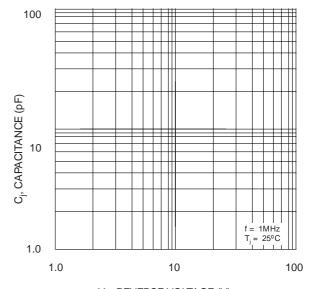


Fig. 2 Typical Forward Characteristics



 V_R , REVERSE VOLTAGE (V) Fig. 4 Typical Junction Capacitance